## BAS316WS

High Speed Switching Diode

## Applications

- High-speed switching

PINNING

| PIN | DESCRIPTION |
| :---: | :--- |
| 1 | Cathode |
| 2 | Anode |



Top View
Marking Code: "W2" Simplified outline SOD-323 and symbol

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ )

| Parameter |  | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Repetitive Peak Reverse Voltage |  | $\mathrm{V}_{\text {RRM }}$ | 100 | V |
| Reverse Voltage |  | $V_{\text {R }}$ | 100 | V |
| Continuous Forward Current |  | $\mathrm{I}_{\text {F }}$ | 250 | mA |
| Repetitive Peak Forward Current |  | $\mathrm{I}_{\text {FRM }}$ | 500 | mA |
| Non-Repetitive Peak Forward Current | $\begin{aligned} & \mathrm{t}=1 \mu \mathrm{~s} \\ & \mathrm{t}=1 \mathrm{~ms} \\ & \mathrm{t}=1 \mathrm{~s} \end{aligned}$ | $\mathrm{I}_{\text {FSM }}$ | $\begin{gathered} 4 \\ 1 \\ 0.5 \end{gathered}$ | A |
| Total Power Dissipation |  | $\mathrm{P}_{\text {tot }}$ | 200 | mW |
| Junction Temperature |  | $\mathrm{T}_{\mathrm{j}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range |  | $\mathrm{T}_{\text {stg }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Characteristics at $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Max. | Unit |
| :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { Forward Voltage } \\ & \text { at } I_{F}=1 \mathrm{~mA} \\ & \text { at } I_{F}=10 \mathrm{~mA} \\ & \text { at } I_{F}=50 \mathrm{~mA} \\ & \text { at } I_{F}=150 \mathrm{~mA} \\ & \hline \end{aligned}$ | $V_{\text {F }}$ | $\begin{gathered} 0.715 \\ 0.855 \\ 1 \\ 1.25 \\ \hline \end{gathered}$ | V |
| $\begin{aligned} & \text { Reverse Current } \\ & \text { at } V_{R}=25 \mathrm{~V} \\ & \text { at } V_{R}=75 \mathrm{~V} \\ & \text { at } V_{R}=25 \mathrm{~V}, \mathrm{~T}_{J}=150^{\circ} \mathrm{C} \\ & \text { at } V_{R}=75 \mathrm{~V}, \mathrm{~T}_{J}=150^{\circ} \mathrm{C} \end{aligned}$ | $I_{\text {R }}$ | $\begin{gathered} 30 \\ 1 \\ 30 \\ 50 \\ \hline \end{gathered}$ | nA $\mu \mathrm{A}$ $\mu \mathrm{A}$ $\mu \mathrm{A}$ |
| Diode Capacitance at $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ | $\mathrm{C}_{\text {tot }}$ | 1.5 | pF |
| Reverse Recovery Time at $I_{F}=I_{R}=10 \mathrm{~mA}, I_{r r}=0.1 \mathrm{XI} \mathrm{I}_{\mathrm{R}}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | $\mathrm{t}_{\text {rr }}$ | 4 | ns |

Dated : 07/04/2009


Fig. 1 Maximum permissible continuous forward current as a function of soldering point temperature.

(1) $\mathrm{T}_{\mathrm{I}}=150^{\circ} \mathrm{C}$; typical values.
(2) $\mathrm{T}_{1}=25^{\circ} \mathrm{C}$; typical values.
(3) $\mathrm{T}_{j}=25^{\circ} \mathrm{C}$; maximum values.

Fig. 2 Forward current as a function of forward voltage.


Rased on square wave currents.
$\mathrm{T}_{\mathrm{j}}=25^{\circ} \mathrm{C}$ prior to surge.
Fig. 3 Maximum permissible non-repetitive peak forward current as a function of pulse duration.


Fig. 4 Reverse current as a function of junction temperature.

$\mathrm{f}=1 \mathrm{MHz} ; \mathrm{T}_{\mathrm{j}}=2 \mathrm{~S}^{\circ} \mathrm{C}$.
Fig. 5 Diode capacitance as a function of reverse voltage; typical values.


MOODY
Cintration mic


## PACKAGE OUTLINE



| UNIT | A | $\mathrm{b}_{\mathrm{p}}$ | C | D | E | $\mathrm{H}_{\mathrm{E}}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| mm | 1.10 | 0.40 | 0.15 | 1.80 | 1.35 | 2.80 |
|  | 0.80 | 0.25 | 0.00 | 1.60 | 1.15 | 2.30 |

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